

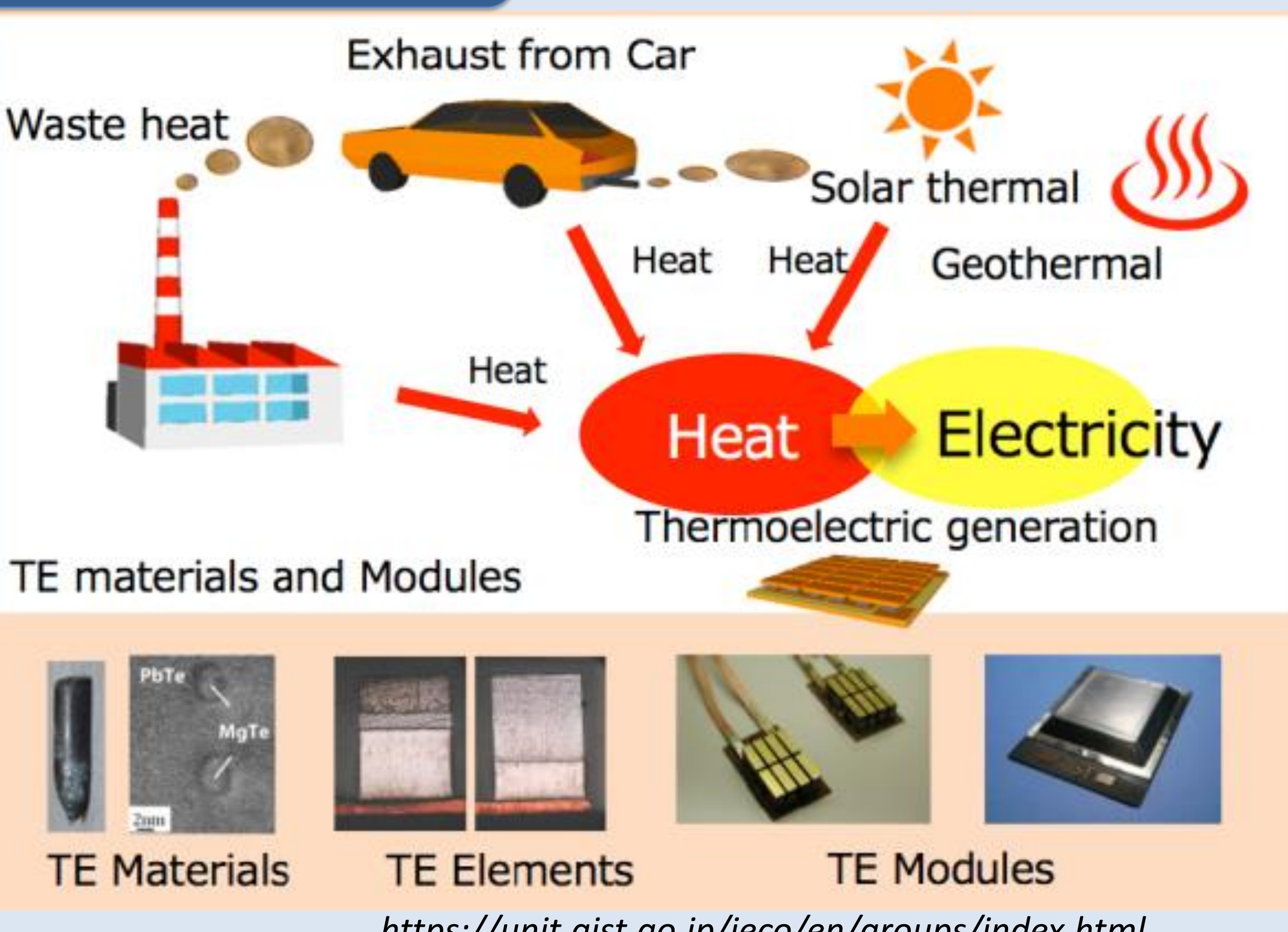
Thermoelectric module interface engineering using Li-NiO/Al-ZnO composites

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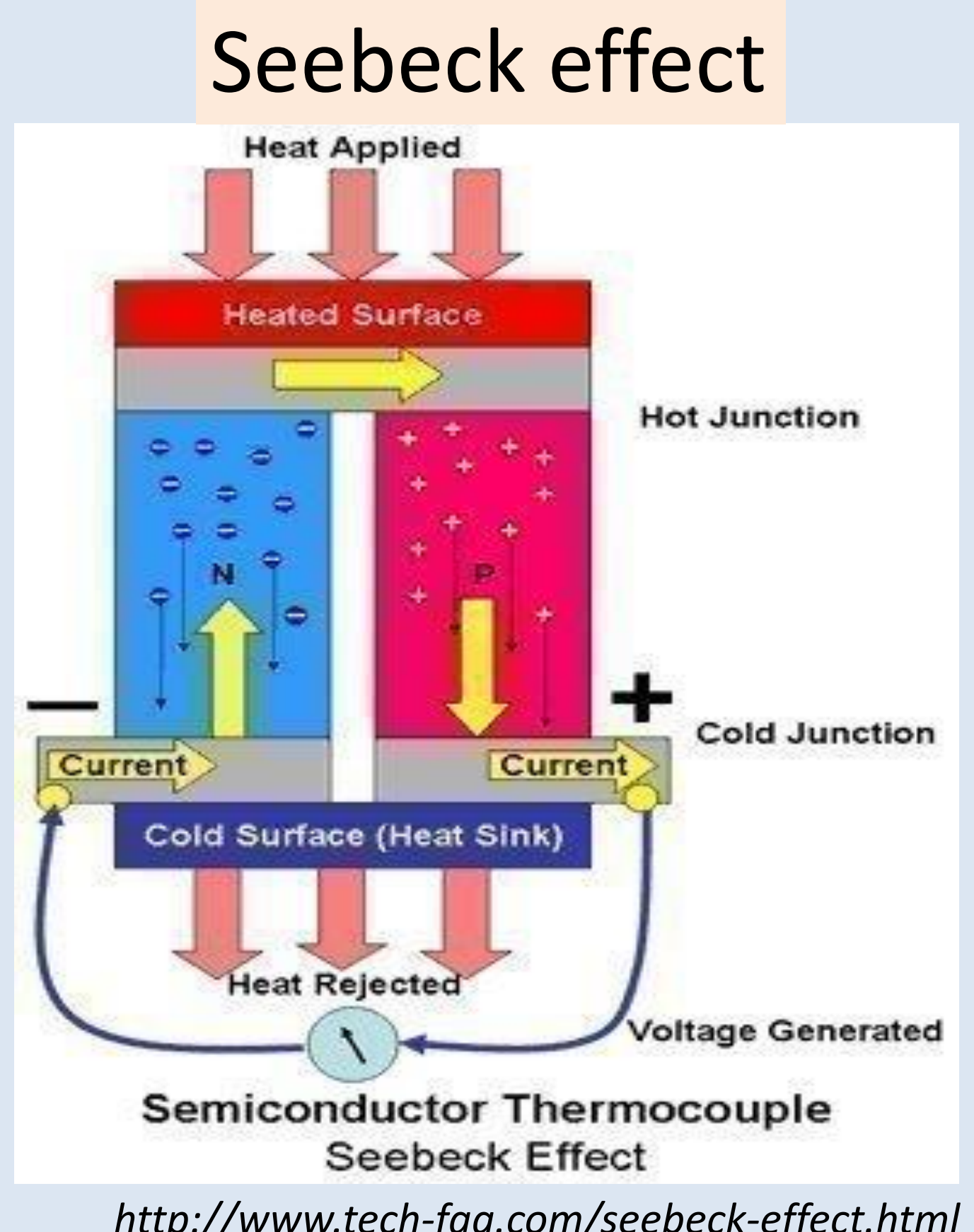


UiO
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1. Introduction



<https://unit.aist.go.jp/ieco/en/groups/index.html>



<http://www.tech-faq.com/seebeck-effect.html>

Device/Module ZT

$$Z_{Device}T = \frac{S_{Device}^2}{k_{Device} R_{Device}} T$$

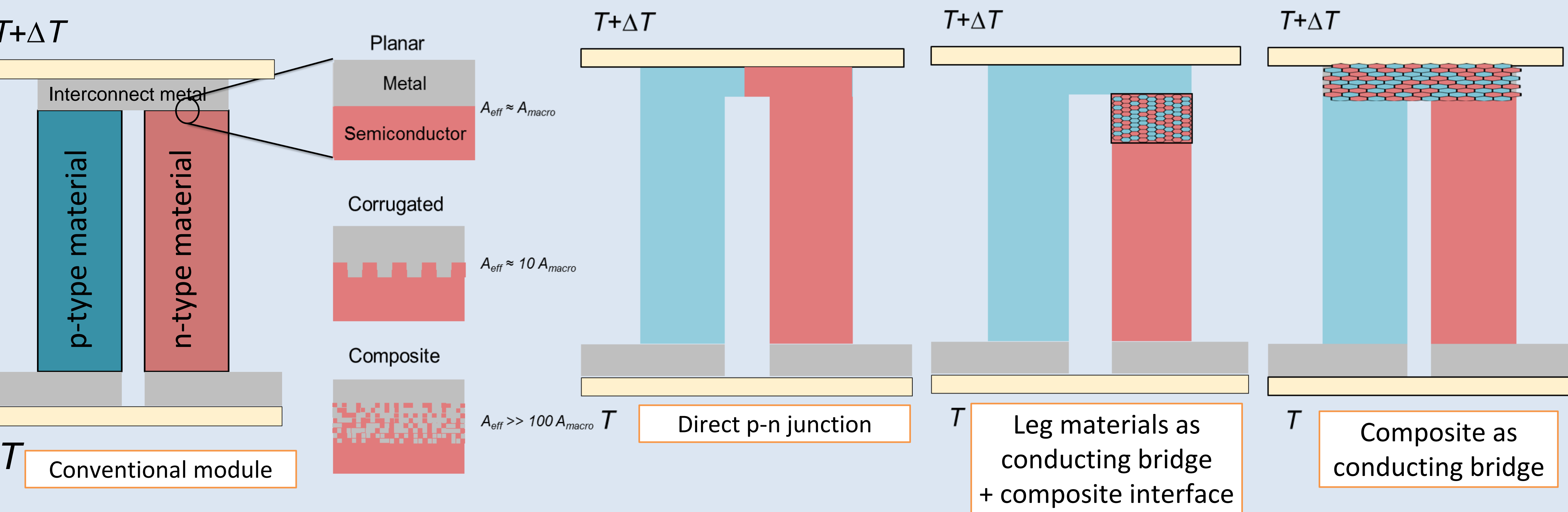
$$S_{Device} = S_p - S_n$$

$$k_{Device} = \frac{A_n}{L} k_n + \frac{A_p}{L} k_p + \frac{A}{k_{contact}}$$

$$R_{Device} = R_{legs} + R_{contact} + R_{interconnect}$$

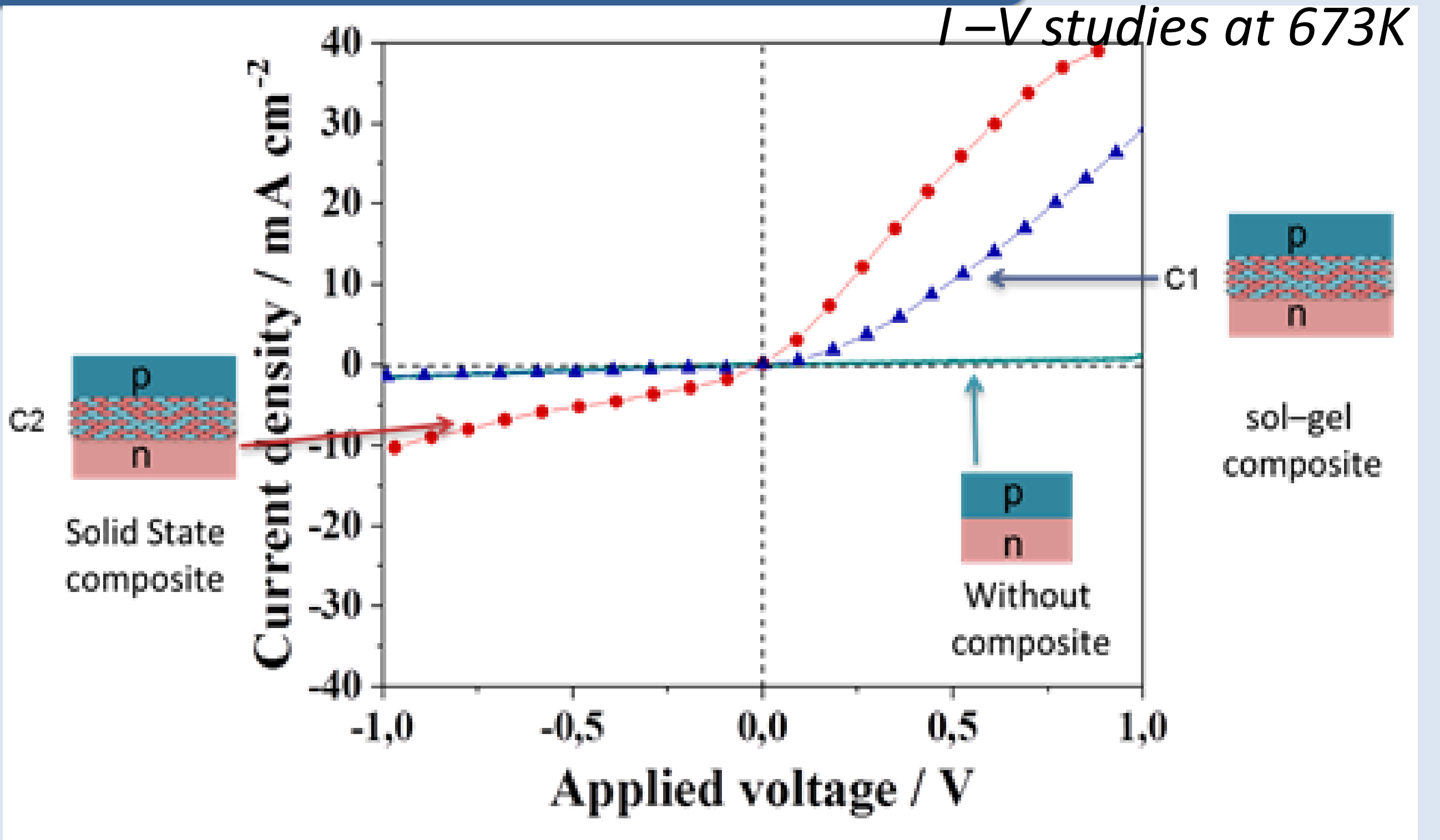
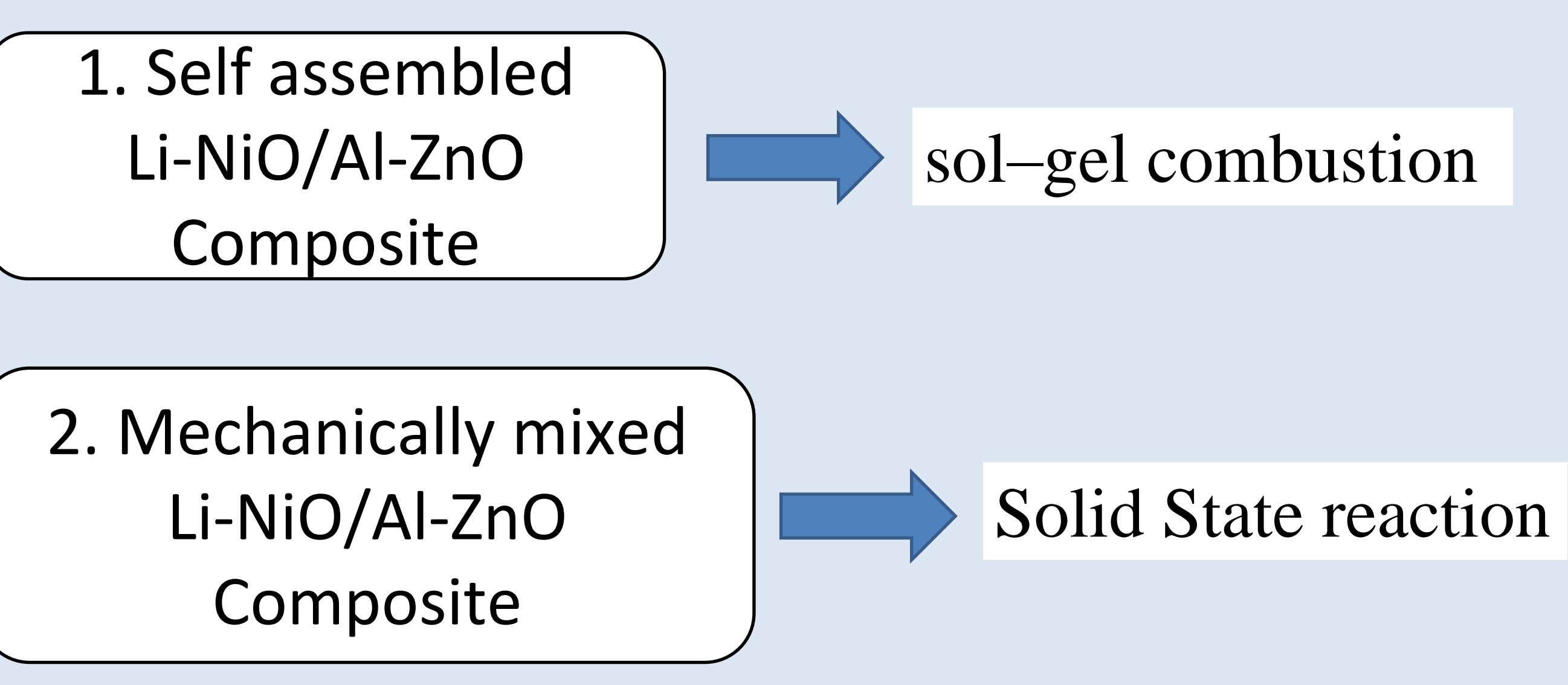
How to minimize the contact resistance

2. Thermoelectric module interface engineering



Same projected area – Higher effective area - Reduces the resistances

3. Li-NiO/Al-ZnO Composite interfaces: What affects resistance and rectification?



4. Conclusions and questions

- **Sol-gel p-n interface composites**
 - More rectifying! Fine microstructures, Sharp (co-existent, equilibrated) interfaces?
- **Solid State p-n interface composites**
 - Less rectifying (more ohmic)! Coarse microstructures, Less perfect (diffused) interfaces?